VS-6EWH06FNHM3

Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 6 A FRED Pt[®]



DPAK (TO-252AA)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	6 A			
V _R	600 V			
V _F at I _F	1.26 V			
t _{rr} (typ.)	18 ns			
T _J max.	175 °C			
Package	DPAK (TO-252AA)			
Circuit configuration	Single			

FEATURES

- Hyperfast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V _{RRM}		600	V
Average rectified forward current	I _{F(AV)}	T _C = 144 °C	6	
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	70	А
Peak repetitive forward current	I _{FM}	$T_{C} = 144 \text{ °C}, f = 20 \text{ kHz}, d = 50 \%$	12	
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	N	
Ferruard voltage	VF	I _F = 6 A	-	1.60	2.1	V	
Forward voltage V _F		I _F = 6 A, T _J = 150 °C	-	1.26	1.7		
Poweree leekage ourrept	1	$V_{R} = V_{R}$ rated	-	-	50		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	μA	
Junction capacitance	CT	V _R = 600 V	-	3.5	-	pF	
Series inductance	LS	Measured lead to lead 5 mm from package body	-	8	-	nH	

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RoHS

COMPLIANT

HALOGEN

FREE







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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \ dI_F/dt = 100$	A/μs, V _R = 30 V	-	18	25	ns A	
Poverse recovery time	+	$I_F = 1 \text{ A}, \ dI_F/dt = 50 \text{ /}$	4/μs, V _R = 30 V	-	22	-		
Reverse recovery time t _{rr}	L ^{rr}	T _J = 25 °C		-	27	-		
		T _J = 125 °C		-	37	-		
Pook rocovory ourront		T _J = 25 °C	$I_F = 6 A$	-	4.1	-		
Peak recovery current I _{RRM}	IRRM	T _J = 125 °C	dl _F /dt = 200 A/µs V _B = 390 V	-	5.3	-		
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	57	-	nC	
	Qrr	T _J = 125 °C		-	103	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case per leg	R _{thJC}		-	-	3	°C/W	
Approximate weight				0.3		g	
				0.01		oz.	
Marking device		Case style DPAK (TO-252AA)		6EWH	06FNH		

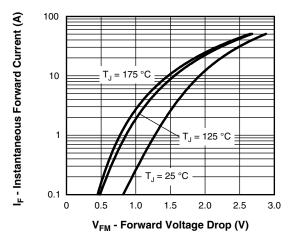
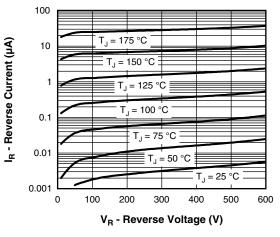
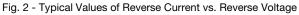
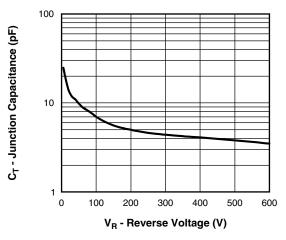
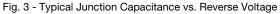


Fig. 1 - Typical Forward Voltage Drop Characteristics









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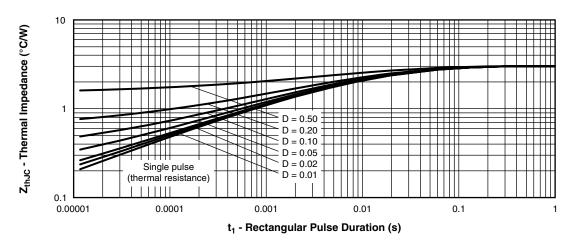
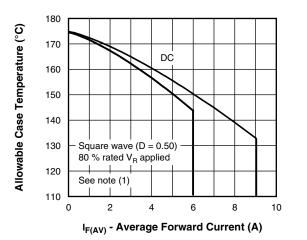
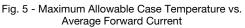
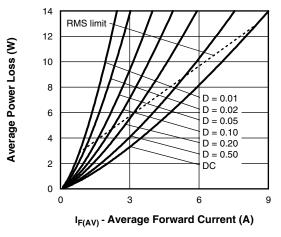


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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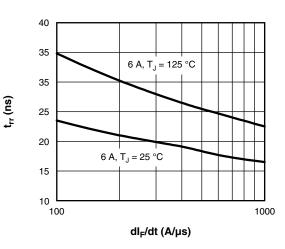
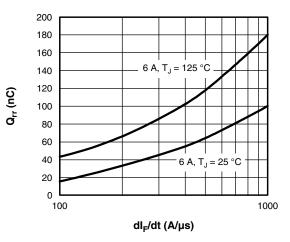
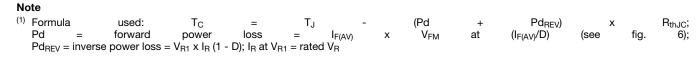


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt







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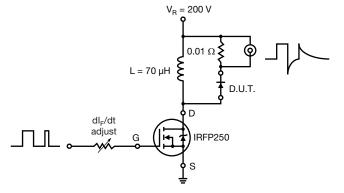
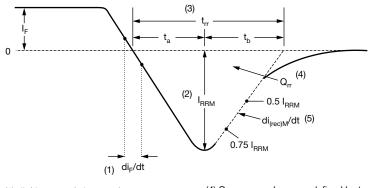


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(2) I_{RRM} - peak reverse recovery current

- (5) $di_{(rec)M}/dt$ peak rate of change of current during t_b portion of t_{rr}
- Fig. 10 Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

		-	-				-			
Device code	VS-	6	E	w	н	06	FN	TRL	н	М3
	1	2	3	4	5	6	7	8	9	10
	1 2 3	 2 - Current rating (6 = 6 A) 3 - Circuit configuration: 								
	4	- Pao W	E = single diode Package identifier: W = D-PAK							
	5 6 7	- Vol - FN	H = hyperfast recovery Voltage rating (06 = 600 V) FN = TO-252AA							
	8	• T	 None = tube TR = tape and reel TRL = tape and reel (left oriented) 							
	9	• T	RR = tap = AEC-C	pe and r	eel (righ		-			
	10		vironme	•		oomolio	nt and	tormino	tionala	ad (Db)

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-6EWH06FNHM3	75	Antistatic plastic tube				
VS-6EWH06FNTRHM3	2000	13" diameter reel				
VS-6EWH06FNTRRHM3	3000	13" diameter reel				
VS-6EWH06FNTRLHM3	3000	13" diameter reel				

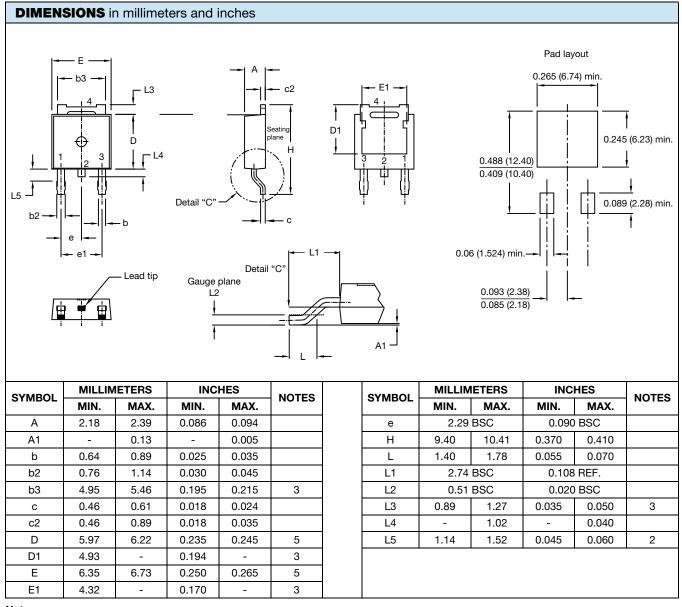
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				

Outline Dimensions



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DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA, except for D1 dimension



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